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December 2014

FCPF190N65FL1 — N-Channel SuperFET<sup>®</sup> II FRFET<sup>®</sup> MOSFET

## FCPF190N65FL1 N-Channel SuperFET<sup>®</sup> II FRFET<sup>®</sup> MOSFET

650 V, 20.6 A, 190 m $\Omega$ 

### Features

- 700 V @T<sub>J</sub> = 150°C
- R<sub>DS(on)</sub> = 168 mΩ (Typ.)
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 60 nC)
- Low Effective Output Capacitance (Typ. Coss(eff.) = 304 pF)
- 100% Avalanche Tested
- RoHS Compliant

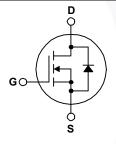
## Applications

- LCD / LED / PDP TV Telecom / Server Power Supplies
- Solar Inverter
- AC DC Power Supply

## Description

SuperFET<sup>®</sup> II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SuperFET II FRFET<sup>®</sup> MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





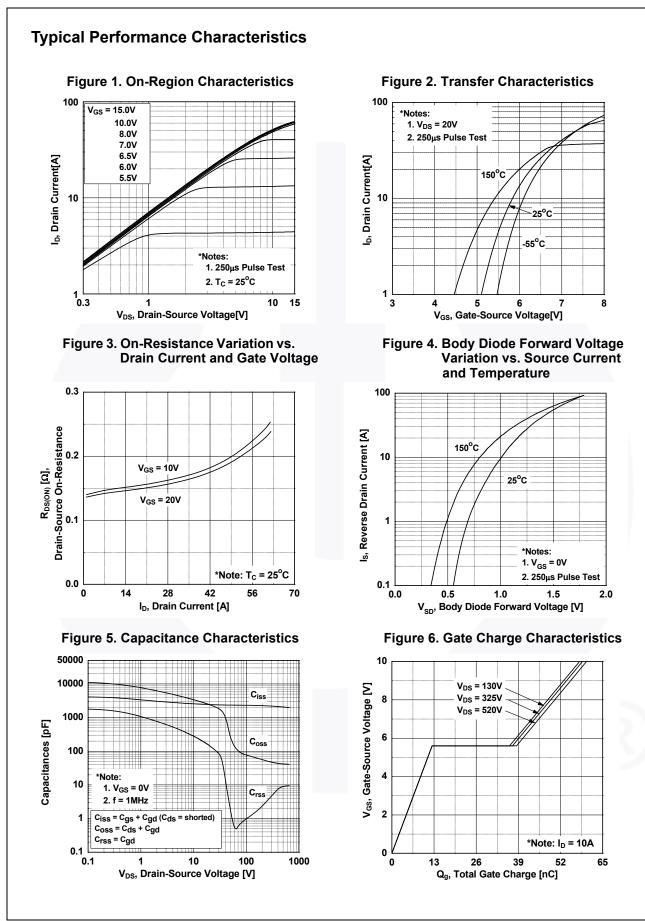
### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FCPF190N65FL1	Unit	
V <sub>DSS</sub>	Drain to Source Voltage		650	V		
		- DC	- DC - AC (f > 1 Hz)		V	
V <sub>GSS</sub>	Gate to Source Voltage	- AC			V	
	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		20.6	•	
I <sub>D</sub>		- Continuous (T <sub>C</sub> = 100°C)	)	13.1	- A	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	61.8	А	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		400	mJ		
I <sub>AR</sub>	Avalanche Current (Note 1)		4	А		
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		0.39	mJ		
dv/dt	MOSFET dv/dt		100	Mag		
uv/ul	Peak Diode Recovery dv/dt		(Note 3)		V/ns	
P <sub>D</sub>	Dower Dissinction	(T <sub>C</sub> = 25°C)		39	W	
	Power Dissipation	- Derate Above 25°C		0.31	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C		
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C		

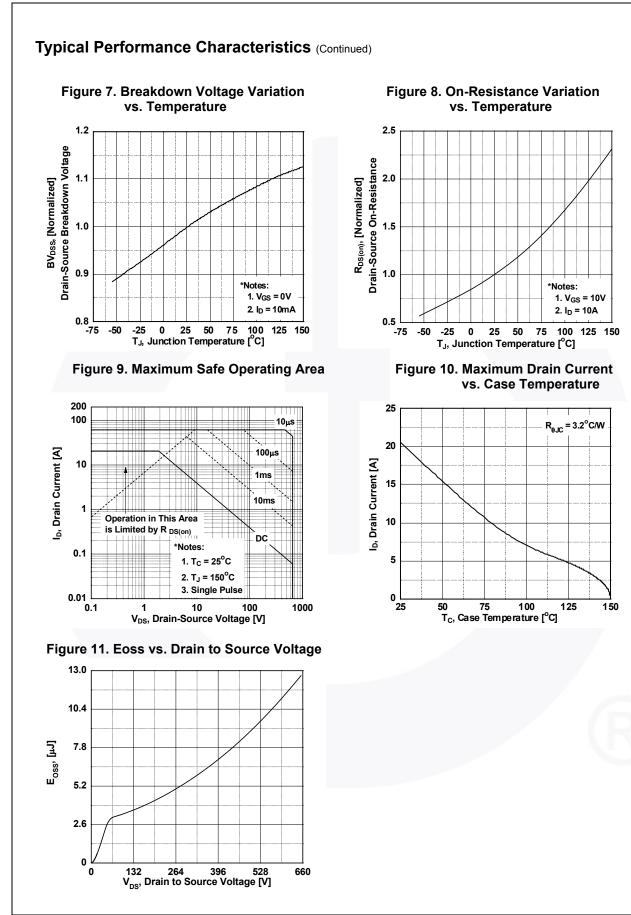
## **Thermal Characteristics**

Symbol	Parameter FCPF190N65FL1		Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.		°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max. 62.5		

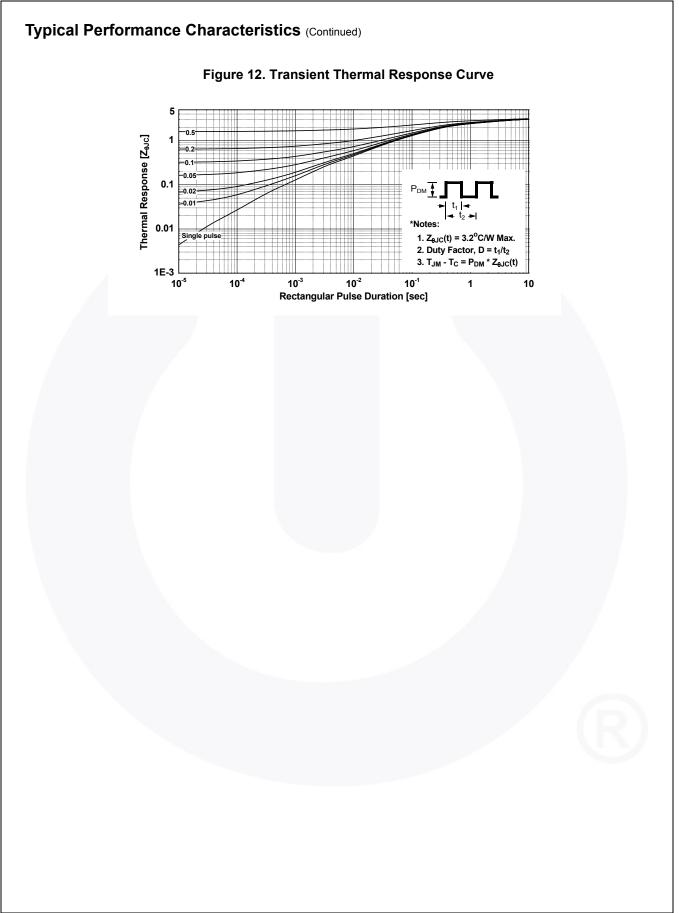
Tube					incity
Tube	N/A	Tape Width N/A		Quantity 50 units	
erwise noted.	1			4	
Test Condi	tions	Min.	Тур.	Max.	Unit
				1	
$V_{GS} = 0 V, I_D = 10 mA, T_J = 25^{\circ}C$		650	-	-	V
V <sub>GS</sub> = 0 V, I <sub>D</sub> = 10 mA, T <sub>J</sub> = 150°C		700	-	-	V
$I_D = 10 \text{ mA}$ , Referenced to $25^{\circ}$ C		-	0.72	-	V/°C
<sub>DS</sub> = 650 V, V <sub>GS</sub> = 0	) V	-	-	10	
$V_{DS} = 650 \text{ V}, V_{GS} = 0 \text{ V}$ - $V_{DS} = 520 \text{ V}, V_{GS} = 0 \text{ V}, T_C = 125^{\circ}\text{C}$ -		60	-	μA	
$r_{SS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0$		-	-	±100	μA
<u>55 120 (, ) D5 (</u>				1100	μι
<sub>3S</sub> = V <sub>DS</sub> , I <sub>D</sub> = 2 mA	A	3	-	5	V
$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$ $V_{DS} = 20 \text{ V}, I_D = 10 \text{ A}$		-	168	190	mΩ
		-	18	-	S
			1		
acitance V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	2350	3055	pF
		-	77	100	pF
		-	0.68	-	pF
$V_{DS}$ = 380 V, $V_{GS}$ = 0 V, f = 1 MHz		-	44	-	pF
$V_{DS}$ = 0 V to 400 V, $V_{GS}$ = 0 V		-	304	-	pF
$V_{DS} = 380 \text{ V}, \text{ I}_{D} = 10 \text{ A},$ $V_{GS} = 10 \text{ V}$ (Note 4) $f = 1 \text{ MHz}$		-	60	78	nC
		-	12	-	nC
		-	25	-	nC
		-	0.6	-	Ω
					r
-280 V I - 10	•	-	25	60	ns
$V_{DD}$ = 380 V, I <sub>D</sub> = 10 A, $V_{GS}$ = 10 V, R <sub>g</sub> = 4.7 $\Omega$		-	11	32	ns
		-	62	134	ns
	(Note 4)	-	4.2	18	ns
orward Current		-	_	20.6	Α
Forward Current		_	-	61.8	A
					V
					ns
V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 10 A, dI <sub>F</sub> /dt = 100 A/μs					nC
			010	1	10
SS	s = 0 V, I <sub>SD</sub> = 10 A	$S_{s} = 0 \text{ V}, \text{ I}_{SD} = 10 \text{ A}$ $S_{s} = 0 \text{ V}, \text{ I}_{SD} = 10 \text{ A},$ $dt = 100 \text{ A}/\mu \text{s}$	;= 0 V, I <sub>SD</sub> = 10 A,	s = 0 V, I <sub>SD</sub> = 10 A, - 105	, = 0 V, I <sub>SD</sub> = 10 A, - 105 -

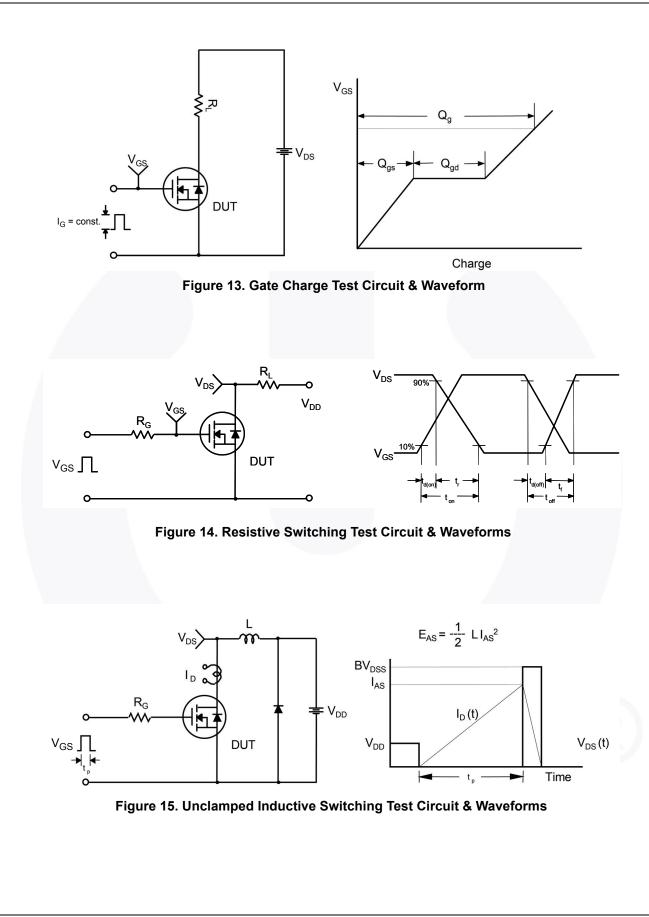


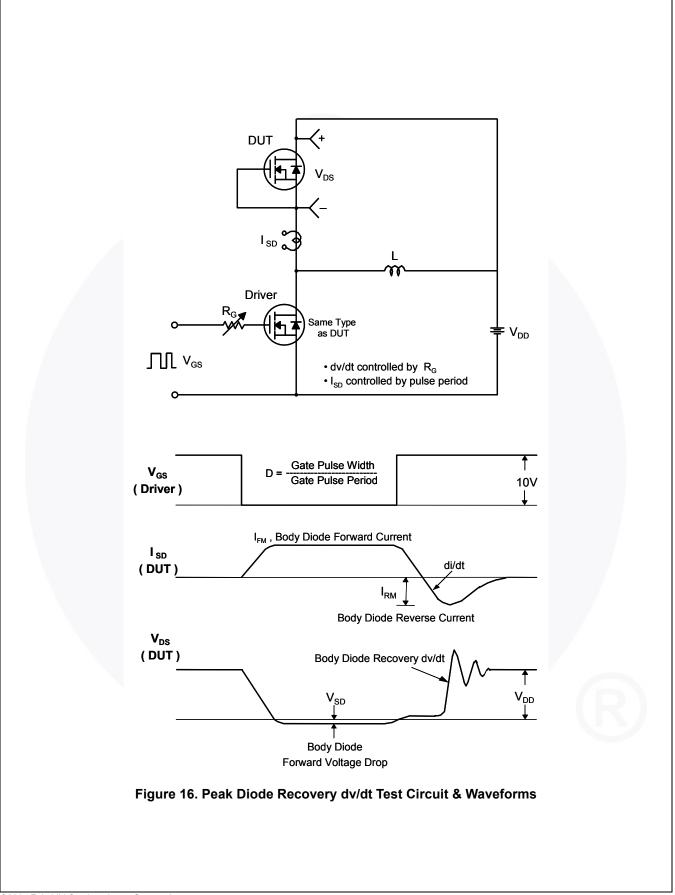
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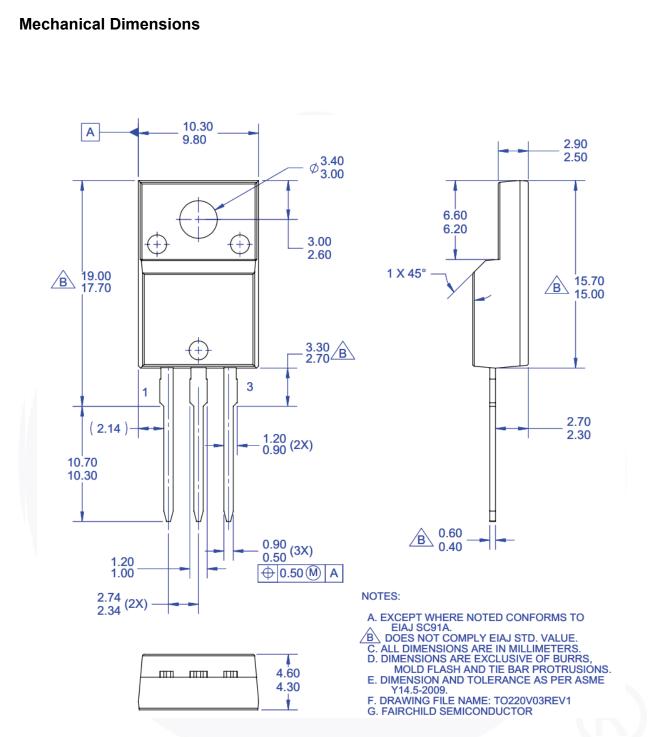


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## Figure 17. TO220, Molded, 3LD, Full Pack, EIAJ SC91, Takcheong

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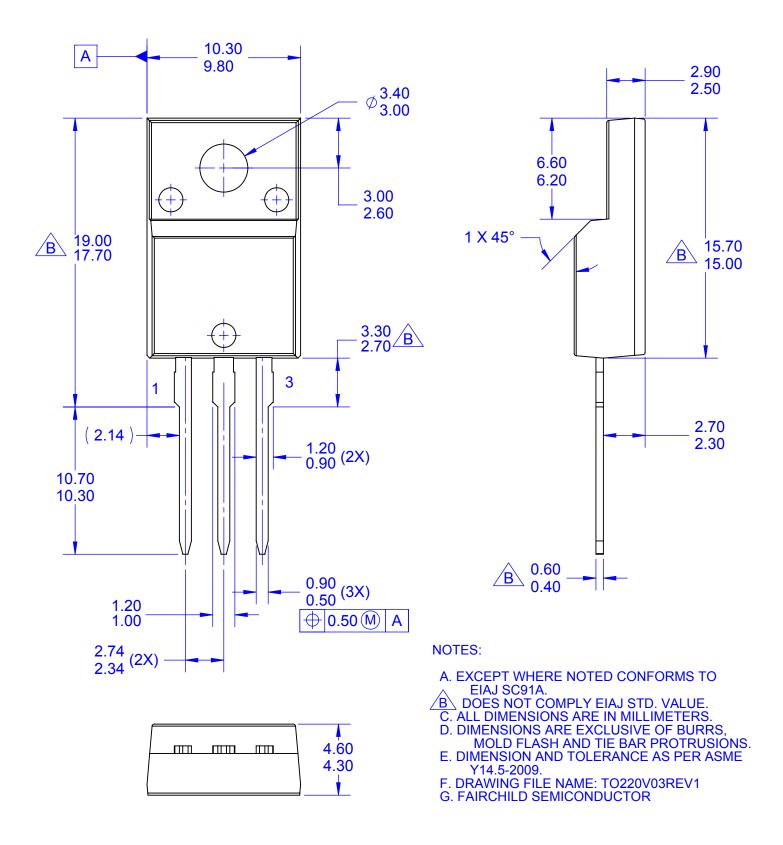
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